

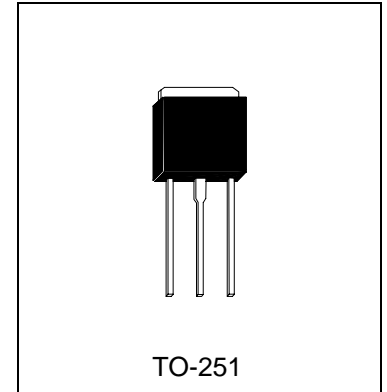


HI32C

PNP EPITAXIAL PLANAR TRANSISTOR

Description

The HI32C is designed for use in general purpose amplifier and low speed switching applications.



Absolute Maximum Ratings (T_A=25°C)

- Maximum Temperatures
 - Storage Temperature -55 ~ +150 °C
 - Junction Temperature +150 °C
- Maximum Power Dissipation
 - Total Power Dissipation (T_C=25°C) 15W
- Maximum Voltages and Currents
 - BV_{CBO} Collector to Base Voltage -100 V
 - BV_{CEO} Collector to Emitter Voltage -100 V
 - BV_{EBO} Emitter to Base Voltage -5 V
 - I_C Collector Current -3 A

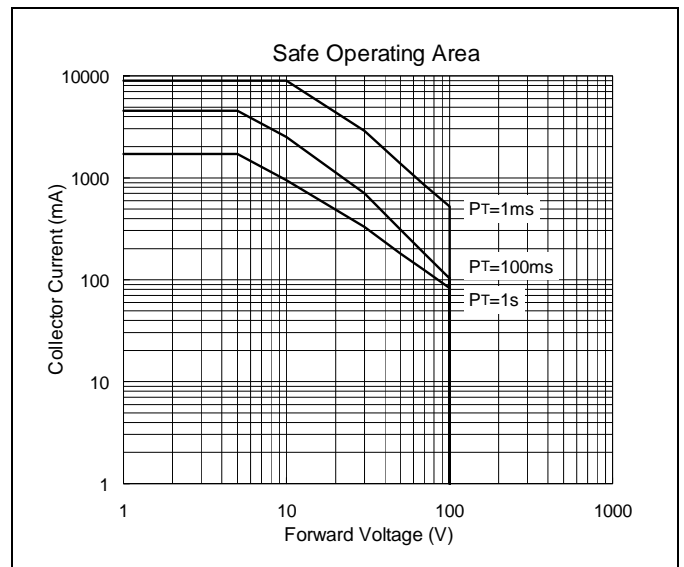
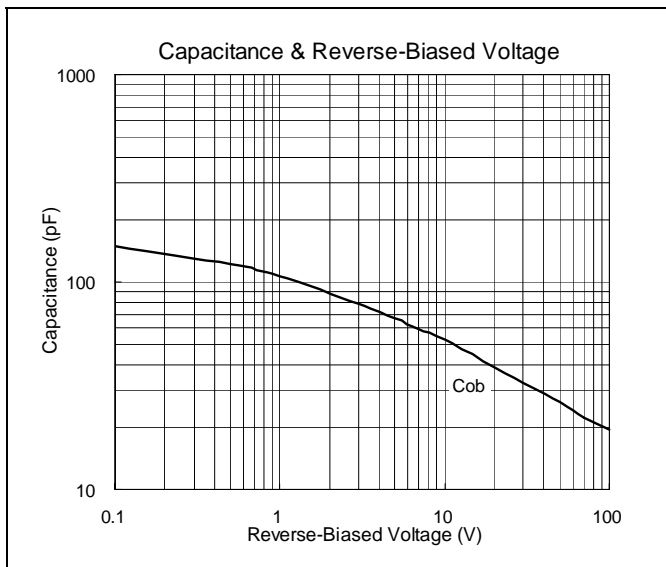
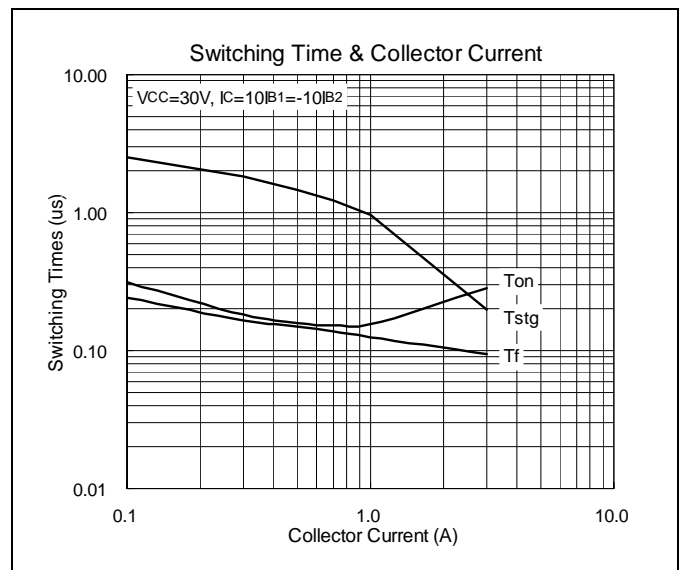
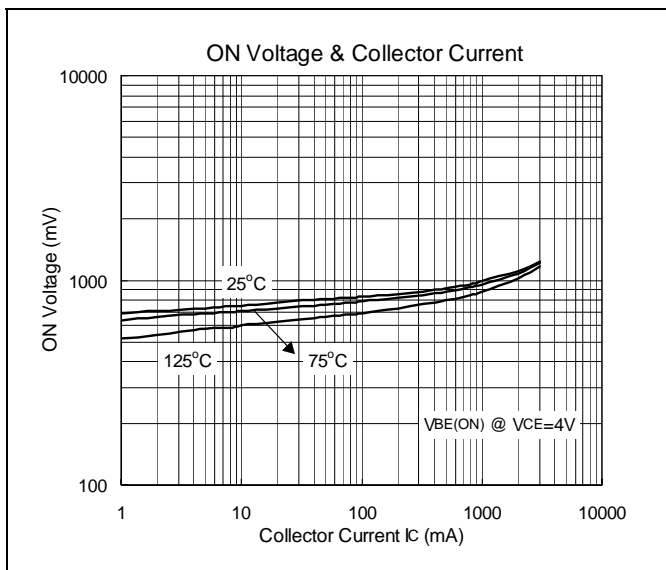
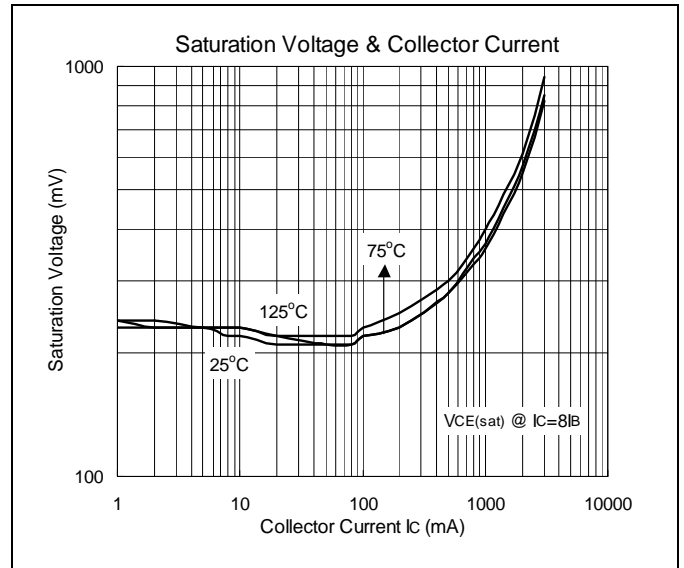
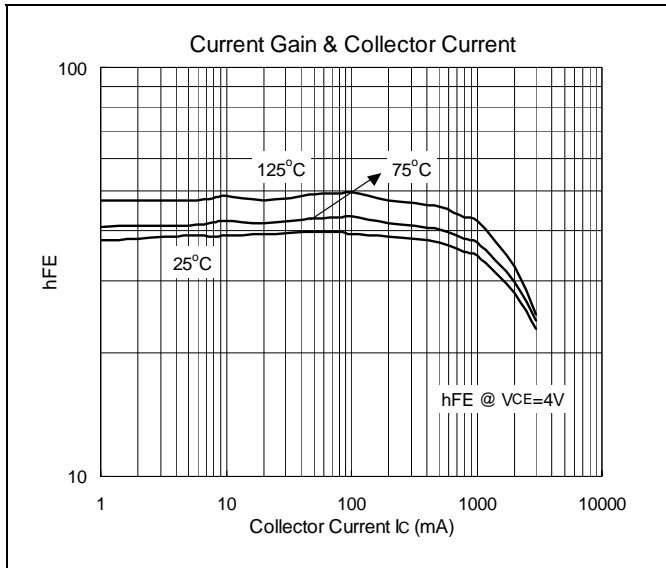
Electrical Characteristics (T_A=25°C)

| Symbol | Min. | Typ. | Max. | Unit | Test Conditions |
|-----------------------|------|------|------|------|---|
| BV _{CBO} | -100 | - | - | V | I _C =-1mA, I _E =0 |
| BV _{CEO} | -100 | - | - | V | I _C =-30mA, I _B =0 |
| I _{CES} | - | - | -20 | uA | V _{CE} =-100V, V _{BE} =0 |
| I _{CEO} | - | - | -50 | uA | V _{CE} =-60V, I _B =0 |
| I _{EBO} | - | - | -1 | mA | V _{EB} =-5V, I _C =0 |
| *V _{CE(sat)} | - | - | -1.2 | V | I _C =-3A, I _B =-375mA |
| *V _{BE(on)} | - | - | -1.8 | V | V _{CE} =-4V, I _C =-3A |
| *h _{FE1} | 25 | - | - | | V _{CE} =-4V, I _C =-1A |
| *h _{FE2} | 10 | - | 50 | | V _{CE} =-4V, I _C =-3A |
| f _T | 3 | - | - | MHZ | V _{CE} =-10V, I _C =-500mA, f=1MHz |

*Pulse Test: Pulse Width ≤380us, Duty Cycle ≤2%



Characteristics Curve





TO-251 Dimension

Marking:

Pb Free Mark
 Pb-Free: "●" (Note)
 Normal: None

Date Code Control Code

Note: Green label is used for pb-free packing

Pin Style: 1.Base 2/Tab.Collector 3.Emitter

Material:

- Lead solder plating: Sn60/Pb40 (Normal), Sn/3.0Ag/0.5Cu or Pure-Tin (Pb-free)
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

| DIM | Min. | Max. |
|-----|------|-------|
| A | 6.35 | 6.80 |
| C | 4.80 | 5.50 |
| F | 1.30 | 1.70 |
| G | 5.40 | 6.25 |
| H1 | 6.75 | 8.00 |
| K | 0.50 | 0.90 |
| K1 | 0.40 | 0.90 |
| L | 0.90 | 1.50 |
| M | 2.20 | 2.40 |
| a1 | 0.40 | 0.65 |
| a2 | - | *2.30 |

*: Typical, Unit: mm

**3-Lead TO-251
Plastic Package
HSMC Package Code: I**

Marking:

Pb Free Mark
 Pb-Free: "●" (Note)
 Normal: None

Date Code Control Code

Note: Green label is used for pb-free packing

Pin Style: 1.Base 2.Collector 3.Emitter

Material:

- Lead solder plating: Sn60/Pb40 (Normal), Sn/3.0Ag/0.5Cu or Pure-Tin (Pb-free)
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

| DIM | Min. | Max. |
|-----|------|--------|
| A | 6.40 | 6.80 |
| B | - | 6.00 |
| C | 5.04 | 5.64 |
| D | - | *4.34 |
| E | 0.40 | 0.80 |
| F | 0.50 | 0.90 |
| G | 5.90 | 6.30 |
| H | - | *1.80 |
| H1 | - | *9.30 |
| I | - | *16.10 |
| J | - | *0.80 |
| K | - | 0.96 |
| K1 | - | *0.76 |
| M | 2.20 | 2.40 |
| a1 | 0.40 | 0.60 |
| a2 | 2.10 | 2.50 |
| y1 | - | 5° |
| y2 | - | 3° |

*: Typical, Unit: mm

**3-Lead TO-251
Plastic Package
HSMC Package Code: I**

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Soldering Methods for HSMC's Products

1. Storage environment: Temperature=10°C~35°C Humidity=65%±15%
2. Reflow soldering of surface-mount devices



| Profile Feature | Sn-Pb Eutectic Assembly | Pb-Free Assembly |
|--|-------------------------|------------------|
| Average ramp-up rate (T_L to T_P) | <3°C/sec | <3°C/sec |
| Preheat | | |
| - Temperature Min (T_{Smin}) | 100°C | 150°C |
| - Temperature Max (T_{Smax}) | 150°C | 200°C |
| - Time (min to max) (t_s) | 60~120 sec | 60~180 sec |
| T_{Smax} to T_L | | |
| - Ramp-up Rate | <3°C/sec | <3°C/sec |
| Time maintained above: | | |
| - Temperature (T_L) | 183°C | 217°C |
| - Time (t_L) | 60~150 sec | 60~150 sec |
| Peak Temperature (T_P) | 240°C +0/-5°C | 260°C +0/-5°C |
| Time within 5°C of actual Peak Temperature (t_P) | 10~30 sec | 20~40 sec |
| Ramp-down Rate | <6°C/sec | <6°C/sec |
| Time 25°C to Peak Temperature | <6 minutes | <8 minutes |

3. Flow (wave) soldering (solder dipping)

| Products | Peak temperature | Dipping time |
|------------------|------------------|--------------|
| Pb devices. | 245°C ±5°C | 5sec ±1sec |
| Pb-Free devices. | 260°C +0/-5°C | 5sec ±1sec |